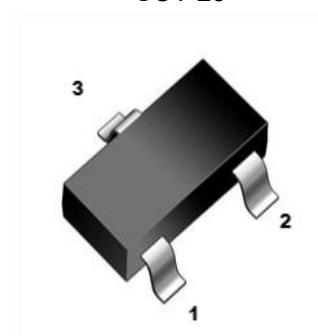




Features

- TrenchFET Power MOSFET

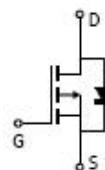
SOT-23



Mechanical Data

- Case:Molded Plastic,SOT-23 .
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking: S5A
- Mounting Position : Any.
- Equivalent Circuit:

1 Gate
2 Source
3 Drain



Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Units
Drain-Source Voltage	V _{DS}	-20	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	-4.2	A
Pulsed Drain Current ¹	I _{DM}	-16.8	A
Power Dissipation	P _D	1.25	W
Thermal Resistance from Junction to Ambient ²	R _{θJA}	112	°C/W
Junction Temperature	T _J	-55~ +150	°C
Storage Temperature	T _{STG}	-55~ +150	°C



Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V _(BR) DSS	V _{GS} = 0V, I _D = -250µA	-20			V
Gate-source threshold voltage ³	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250µA	-0.4		-1	
Gate-source leakage current	I _{GSS}	V _{DS} = 0V, V _{GS} = ±10V			±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -20V, V _{GS} = 0V			-1	µA
Drain-source on-resistance ³	R _{D(on)}	V _{GS} = -4.5V, I _D = -3A		34	42	mΩ
		V _{GS} = -2.5V, I _D = -2A		42	54	
Dynamic Characteristics⁴						
Input capacitance	C _{iss}	V _{DS} = -10V, V _{GS} = 0V, f = 1MHz		854		pF
Output capacitance	C _{oss}			150		
Reverse transfer capacitance	C _{rss}			90		
Total gate charge	Q _g	V _{DS} = -10V, V _{GS} = -10V, I _D = -3A		9.6		nC
Gate-source charge	Q _{gs}			1.6		
Gate-drain charge	Q _{gd}			2		
Turn-on delay time	t _{d(on)}	V _{DS} = -15V, I _D = -1A V _{GS} = -4.5V, R _G = 3Ω		11		ns
Turn-on rise time	t _r			34		
Turn-off delay time	t _{d(off)}			51		
Turn-off fall time	t _f			14		
Source-drain diode characteristics and maximum ratings						
Diode forward voltage ³	V _{SD}	I _S = -2A, V _{GS} = 0V			-1.2	V

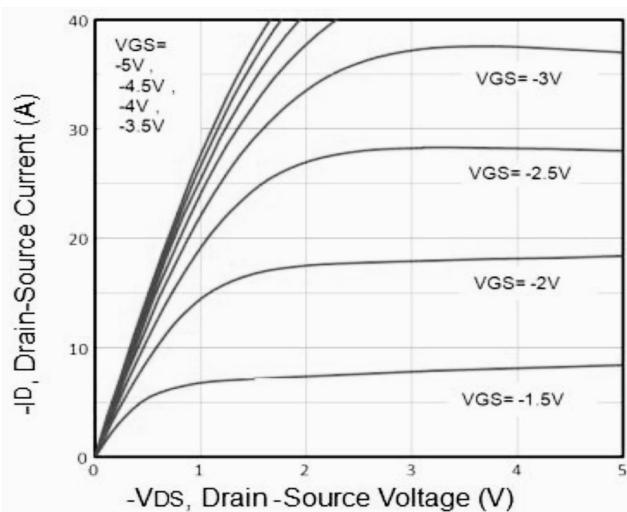
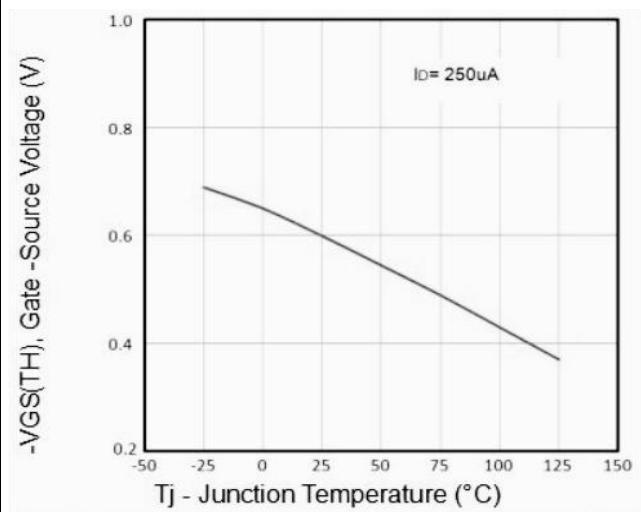
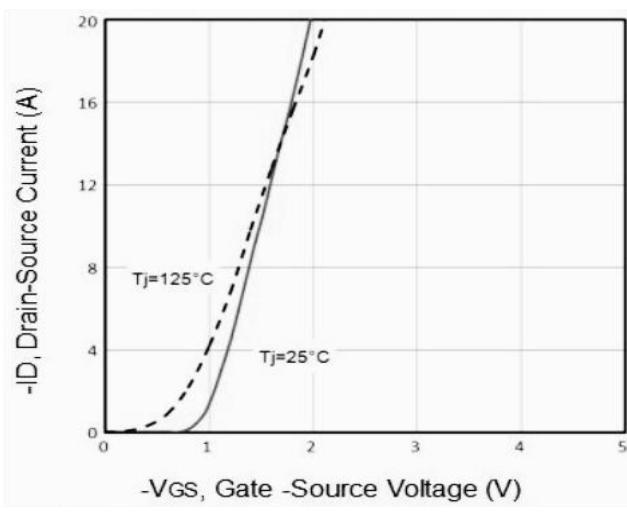
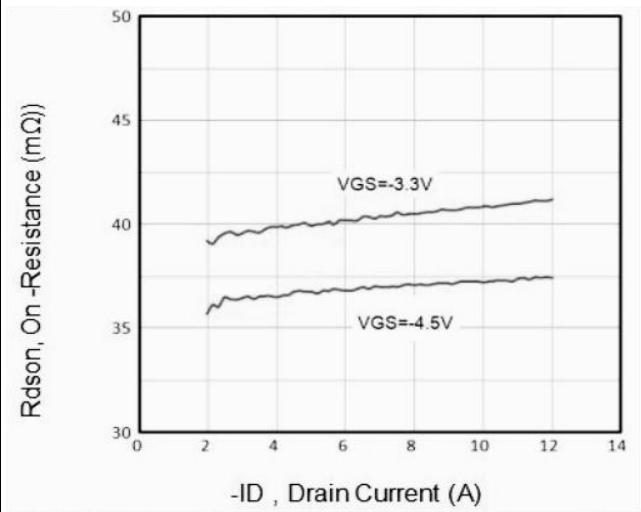
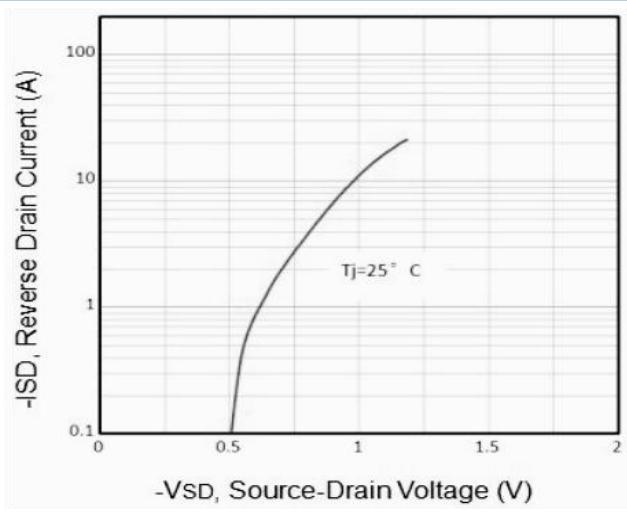
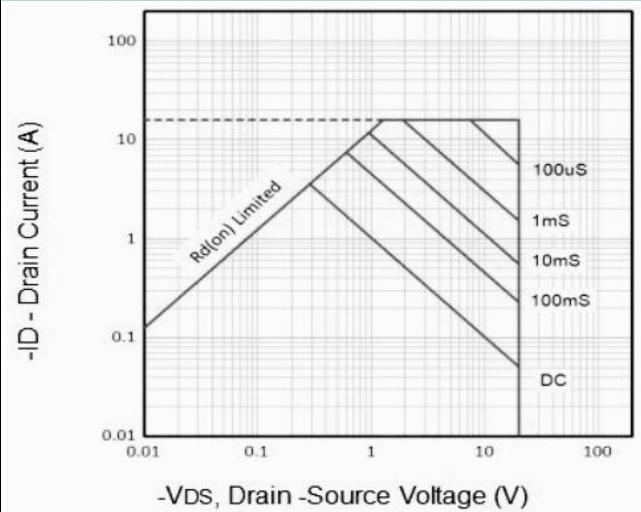
Note :

1. Repetitive rating: Pulse width limited by maximum junction temperature
2. Surface Mounted on FR4 board, t≤10 sec.
3. Pulse test : Pulse width≤300µs, duty cycle≤2%.
4. Guaranteed by design, not subject to production.

**XN2305A**

20V P-Channel MOSFET

Rating And Characteristic Curves

Fig.1 Static Characteristic**Fig.2 Normalized Threshold Voltage vs. Temperature****Fig.3 Typical Transfer Characteristics****Fig.4 On-Resistance vs. Drain Current and Gate Voltage****Fig.5 Typical Source-Drain Diode Forward Voltage****Fig.6 Maximum Safe Operating Area**



Rating And Characteristic Curves

Fig.7 Typical Capacitance vs. Drain-Source Voltage

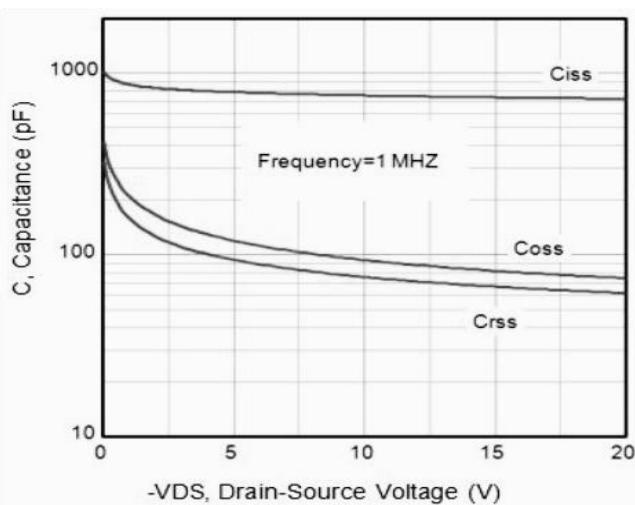
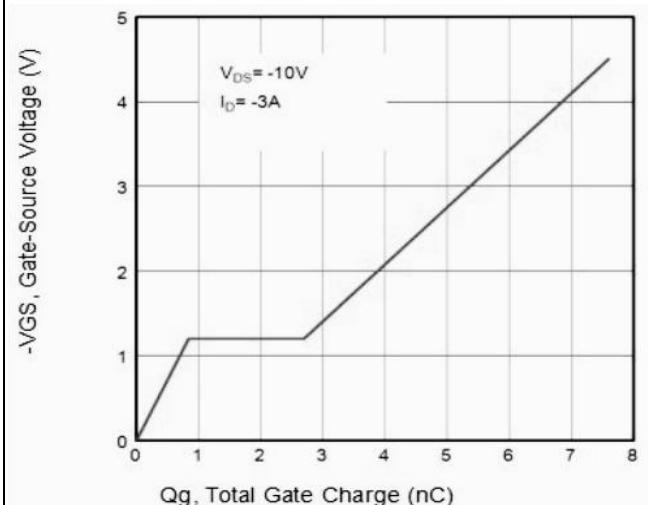
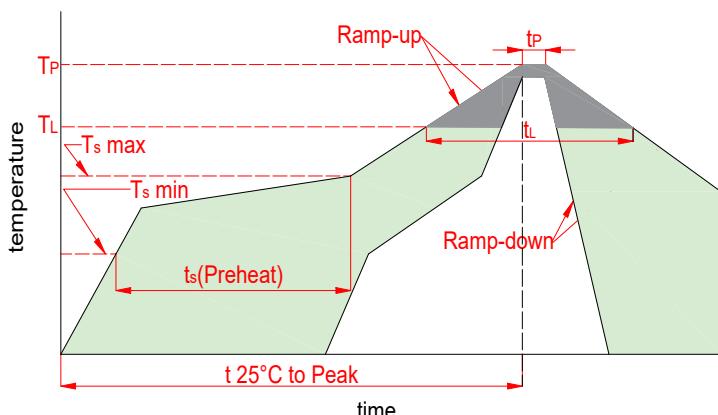


Fig.8 Typical Gate Vs. Gate-Source Voltage



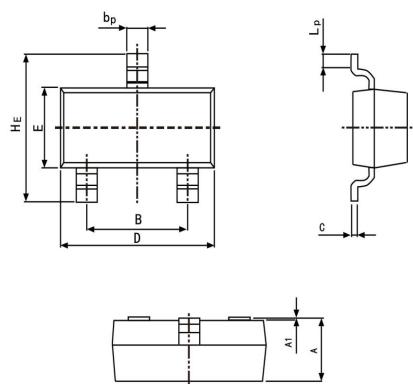


6. Soldering Parameters

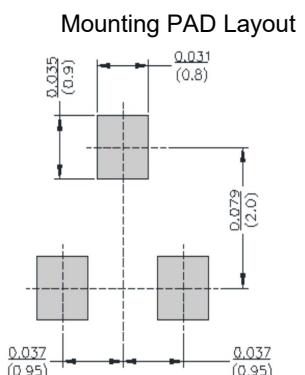


Reflow Condition		Lead-free
Pre Heat	Temp. min(T_s (min))	150°C
	Temp. max(T_s (min))	200°C
	Time(min to max)(t_s)	60~120s
Aver. ramp up rate(Liquidus Temp.)(T_L)to peak		3°C/s max
	T_s (max) to T_L -Ramp-up Rate	3°C/s max
Reflow	Temp.(T_L)(Liquidus)	217°C
	Temp.(t_L)(Liquidus)	60~150s
Peak Temp.(T_p)		260 ^{+0/-5} °C
Time within actual peak Temp.(t_p)		30s max
Ramp-down Rate		6°C/s max
Time 25°C to peak Tempe.(T_p)		8 minutes max
Do not exceed		260°C

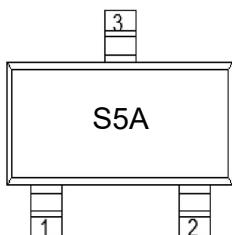
7. Dimensions



Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.035	0.045	0.90	1.15
B	0.070	0.081	1.78	2.05
bp	0.012	0.020	0.30	0.51
C	0.003	0.007	0.08	0.18
D	0.110	0.118	2.80	3.00
E	0.047	0.055	1.20	1.40
HE	0.087	0.110	2.20	2.80
A1	0.000	0.004	0.00	0.10
LP	0.008	0.020	0.20	0.50



8. Part Marking System



9. Package Information

Package	Part Number	Tape Width(mm)	Quantity(pcs)
SOT-23	XN2305A	8	3000



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